Josephson e ect in superconducting constrictions with hybrid SF electrodes: peculiar properties determ ined by the misorientation of magnetizations

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Josephson current in SFcFS junctions with arbitrary transparency of the constriction (c) is investigated. The emphasis is done on the analysis of the supercurrent dependencies on the misorientation angle—between the in-plane magnetizations of disciplined agnetic layers (F). It is found that the current-phase relation I (′) may be radically modified with the variation: the harmonic $I_1 \sin \prime$ vanishes for de nite value of—provided for identical orientation of the magnetizations (= 0) the junction is in the " "state. The Josephson current may exhibit a nonmonotonic dependence on the misorientation angle both for realization of "0" and " "state at = 0. We also analyze the elect of exchange—eld induced enhancement of the critical current which may occur in de nite range of

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The dc Josephson e ect in junctions with ferrom agnetic interlayers (F) exhibit exchange eld induced remarkable features, namely, the transition from a "0" state to a " " state of junctions [1, 2], enhancement of the critical Josephson current β, 4] and others. These features have been intensively studied in recent years theoretically and experimentally (see Reviews [5,6,7] and Refs. therein). In spite of a lot of works devoted to this problem there are several important ones which require additional investigation. The purpose of the present work is the study of one of these problems. N am ely we investigate the Josephson current and peculiar properties of SF cFS junctions (c denotes a constriction) with arbitrary misorientation angle between the in-plane oriented magnetizations of the ferrom agnetic metal (F) layers. This investigation is important because the supercurrent is very sensitive to the mutual orientation of magnetizations and, besides, because the variation of gives additional opportunity to switch experimentally between the "0" and " " states. In the considered junctions the constriction is an insulator characterized by the arbitrary transparency or short (in comparison with the coherence length) di usive metal channel. For the Flayers the dirty limit, i.e. di usive regim e of electron transport is assum ed. Note that for the case of ballistic transport through the F layers of quantum S-FIF-S contacts with arbitrary misorientation angle between the magnetizations in the F layers the Josephson current has been studied by Barash et al. [8]. In the present paper we investigate the angle -dependence of dierent peculiar properties of the supercurrent in SFcFS junctions. We show that variation of may result in the transition between the "0" and " " states and the disappearance of $I_1 \sin \prime$ harm onic of the supercurrent for certain value of . E ect of exchange eld induced enhancement of the critical current and its nonmonotonic dependence on the angle are also studied.

As a model of the constriction, we consider an aperture of a small radius in a thin impenetrable screen dividing two dierent electrodes. The constriction is supposed to include a barrier with the transparency D = D (#); where # is the angle between the electronic trajectory and normal to the junction plane. Consider rst the case of ballistic constriction of small size assuming that its radius is small in comparison with l_F ; $v_F = i$; where l_F and v_F ; are the mean free path and Fermi velocity in the F layers, d_F is their thickness, is the energy gap in the superconductors. Under these assumptions the current may be expressed through the M atsubara G reen's functions of the F layers $\hat{G}_{1:2}$ as follows [9, 10, 11]:

$$I(') = \frac{8 \text{ T}}{\text{eR}_0} \sum_{n=0}^{X^{1/2}} hJ(!_n)i; \qquad (1)$$

$$J = \frac{D}{4} Tr^{\circ}_0 \qquad \hat{3} \frac{\hat{G} \hat{G}_+}{(1 - D)\hat{1} + D \hat{G}_+^2} = \frac{D}{4} Tr^{\circ}_0 \qquad \hat{3} \frac{[\hat{G}_2; \hat{G}_1]}{2(2 - D)\hat{1} + D [\hat{G}_2; \hat{G}_1]_+};$$

where $!_n = T(2n+1)$ is the M atsubara frequency, $\hat{G} = (\hat{G}_2 - \hat{G}_1) = 2$; $[\hat{G}_2; \hat{G}_1] = \hat{G}_2\hat{G}_1 - \hat{G}_1\hat{G}_2$; $R_0 = 4^{-2} \sim 3 = (e^2p_F^2A)$ is the Sharvin resistance of the contact, A being the area of the contact, angular brackets denote angular-averaging $h(:::)i = 2^{-1}_{0}$ (:::) $\cos \# d\cos \#$; $^{-1}_{k}$ and $^{-1}_{k}$ are the Pauli (k = 1; 2; 3) or unite (k = 0) m atrices in the spin and particle-hole spaces, respectively, $\hat{1} = \hat{0} - \hat{0}$ As was noted above we consider the case of dirty thin F layers, i.e. their thickness is supposed to satisfy the conditions $l_F - d_F - (^{-1}_{F} = T_c)^{1-2}$ where D_F is the di-usive coe-cient in the F-layers, T_c is the critical temperature of the superconductors. For such layers the space variation of the G-reen's functions is negligible therefore they are given by the expression $\hat{G}_j = \exp(i'_j \hat{0}_j = 2)\hat{0}_j \exp(-i'_j \hat{0}_j = 2)$, where $\hat{0}_F - \hat{0}_F = \hat{0}_F$ is the phase of the order parameter of the jth S-electrode and $\hat{0}_j$ is determined by the following

equation (for details of the derivation see, e.g., [12]):

$$[\hat{g}_{i};! \hat{s}_{3} + i \hat{h}_{i} \hat{S} + "_{b} \hat{g}_{S}]_{+} = \hat{0}$$
(2)

where " $_b$ = ~hD $_b$ i v $_F$ =4d $_F$ = D $_F$ =2R $_b$ $_F$ d $_F$; D $_b$ and R $_b$ are, respectively, the transparency and the resistance per unite area of the S-F interface, $_F$ is the conductivity of the F m etal, d $_S$ is the G reen's function of the superconductors at the S-F interfaces, h_{1;2} are the exchange elds in the F layers, the matrix vectors is dened as [13, 14]s = ^ ^+ ^2 ^2 ^2 ^*; where ^= (^1; ^2; ^3); ^= (^0 ^3)=2:N ote that the value of the exchange elds, $^1_{1,2}$ j = h is supposed to be small with respect to ^-_F and the Fermi energy of the F layers, where $_F$ = 1_F =v $_F$; for considered here dirty layers ^-_F . We assume for simplicity that the S-F interfaces are identical and that their transparency D $_b$ is small, therefore the elect of the F layers on the superconductors is negligible. The only difference between the F layers is related with the orientations of the exchange elds, h $_{1;2}$; which being parallel to the layers, make an angle with each other. In this paper we cone ne ourselves to the case of conventional s-wave superconductors. Therefore to carry out further calculations it is convenient to represent the current with the use of the transform ed G reen's functions 1_F = exp (i' 1_F 3 =2) 1_F exp (i' 1_F 3 =2) where

$$\hat{g}_{i} = \hat{U} \hat{g}_{i} \hat{U}^{-1}; \qquad (3)$$

 $\hat{U} = (\hat{0}_0 + \hat{1}_2 + \hat{0}_2)$: Taking into account that particle (hole) projection matrices, $\hat{0}_+ (\hat{0}_+)$ obey the relation $\hat{0}_+ \hat{0}_+ \hat{0}_+ \hat{0}_+$ it is easy to check that \hat{U}_+ is the unitary H erm itian matrix, $\hat{U}_+ \hat{U}_+ \hat{0}_+ \hat{0}_+$: From (3), (2) one cannot the representation for $\hat{0}_1$ with the help of the projection matrices in the spin space, $\hat{P}_+ \hat{0}_+ \hat{0}_+ \hat{0}_+$ one cannot unite vectors $\hat{0}_1 = \hat{0}_+ \hat{0}_+$; Taking into account the relation $\hat{P}_+ \hat{0}_+ \hat{0}_+$ (n) $\hat{P}_+ \hat{0}_+ \hat{0}_+$ in $\hat{P}_+ \hat{0}_+ \hat{0}_+$ is we get

$$\hat{g}_{j} = \overset{X}{\hat{g}} \qquad \hat{p} \quad (n_{j}) = \frac{1}{2} (\hat{g}_{+} + \hat{g}_{-}) \qquad \hat{g}_{0} + \frac{1}{2} (\hat{g}_{+} - \hat{g}_{-}) \qquad n_{j} \hat{g}_{j}, \tag{4}$$

where $\hat{g} = g^3 + f^2 = 1$;

$$g = \frac{L}{r}; f = \frac{F}{r};$$
 (5)

= $\frac{p}{k^2 + \frac{2}{F}}$; $k = l + i h + l_b g_S(l)$; $k = l_b f_S(l)$: The form of the G reen's function representation (4) does not depend on the special coexpressions for g; it is valid for spatially-hom ogeneous orientation of the exchange elds in the F layers. Note that being written via the transformed matrices g_j ; the expression for the current coincides with (1). The advantage of the representation (4) is related with signicant simplication of the matrix structure of the G reen's functions which are given by sum of two terms determined by the direct product of matrices in the particle-hole and spin spaces. With the help of (4) we get

$$[\hat{G}_{2}; \hat{G}_{1}] = \frac{1}{2} X \qquad [\hat{G}_{2}; \hat{G}_{1}]_{+} \qquad [\hat{F}_{n_{2}}; \hat{F}_{n_{1}}]_{+} \qquad [\hat{G}_{2}; \hat{G}_{1}]_{+} \qquad [\hat{$$

where $\hat{G}_{j} = g^{3} + \exp(i \frac{1}{j} g) f^{2}$. Taking into account that

$$\mathbb{P}^{\hat{}} (n_2); \mathbb{P}^{\hat{}} (n_1)]_{+} = \frac{1}{2} [\mathbb{I} + n_2 n_1 + (n_2 + n_1)^{\hat{}}];$$

$$\mathbb{P}^{\hat{}} (n_2); \mathbb{P}^{\hat{}} (n_1)] = \frac{i}{2} [n_2 \quad n_1]^{\hat{}};$$
(7)

after som e calculations we obtain the following expression for the current

$$I(') = \frac{8 \text{ T sin '}}{eR_0} \sum_{n=0}^{x^{\frac{1}{2}}} \frac{A(')}{B_0 [A_0 + A(')] \sin^2 \frac{r}{2}} + hI(';D)i;$$
(8)

where $' = '_2$ $'_1$; A $(') = A_0 + A_1 \sin^2 \frac{'}{2}$;

$$A_0 = 2D \ 2\cos^2 \frac{1}{2} Ref^2 + \sin^2 \frac{1}{2} jf_j^2 (2 + Dq);$$

 $A_1 = 4D^2 jf_j^4; B_0 = 2 + D \sin^2 \frac{1}{2} q^2; q = jg_j^2 + jf_j^2 1;$

here $g = g (!_n)$; $f = f (!_n)$: Eq. (8) is signi cantly simpli ed for the cases of parallel (p) and antiparallel (a) magnetizations:

$$I = \frac{8 \text{ T sin'}}{\text{eR}_0} \overset{X^{1}}{\text{e}} \overset{\text{(}}{\text{Be D f}^2 = [1 \text{ D f}^2 \text{ sin}^2 \frac{'}{2}]; p}{\text{2D jf j}^2 = [2 + D (jgj^2 + jfj^2 \cos')]; a}$$
(9)

Note that for the case = 0 Eq.(9) reduces to the result obtained in Ref.[18]. In general case the m isorientation angle dependence of the current is rather nontrivial if the transparency D is not small: it does not reduce to the expression (if h_1 , h_2) [15]

$$I(') = I^{(p)}(') \cos^2 \frac{1}{2} + I^{(a)}(') \sin^2 \frac{1}{2} :$$
 (10)

Simple form for the dependence (10) is valid only in the lim it of small transparencies (when $I^{(p;a)}$ (') = $I^{(p;a)}$ sin'); for this case it was rst obtained in Ref.[3].

For num erical analysis of the Josephson current we apply the obtained results assuming that superconductors are described by the BCS theory therefore $q_S(!) = ! = (!^2 + 2)^{1-2}$; $f_S(!) = = (!^2 + 2)^{1-2}$. The results of numerical calculations of I (') -dependences for a junction with the transparency D = 0.5 are presented in Fig.1 for a set of values of . It shows that the function I ($^{\prime}$) m ay strongly deviate from the $\sin{^{\prime}}$ dependence and is strongly modi ed with increasing angle , especially in the vicinity of m isorientation angle = 0 (temperature T_0) which corresponds to the transition between the "0" and " " states of junction. Note that the model with the angle-independent transparency corresponds to the case of quantum single-mode constriction with the resistance $R_0 = -e^2$. At (tem perature T) which with the accuracy higher than 5 percents coincides with the value $_0$ (T $_0$) the harm onic $I_1 \sin'$ of the current (I(') = $I_1 \sin' + I_2 \sin(2') + ...$) vanishes; the sign of I_1 is changed with the variation of (or tem perature) near (T): Living the detailed analysis of supercurrent tem perature dependences for a separate presentation we show here the typical phase diagram of the junction (Fig 2) for not too small exchange elds (in comparison with "). A nother interesting property of the supercurrent is nonmonotonic dependences of the critical current $I_c = m ax I(') jas a function of the angle . Note that a similar behavior of the critical current for$ quantum S-FIF-S junctions with the ballistic transport through the F layers has been analyzed in [8]. We nd that in junctions with diusive Flayers the nonmonotonic dependence $\{()\}$ (Fig.3) may occur for realization of both "" and "0" state for identical orientation of the magnetizations (unlike the case studied in [8]). The results of numerical calculations of the I_c (h) dependences for a low transparency junction at various angle are presented in Fig.4. It shows that the ratio $I_c(h)=I_c(0)$ may exceed unity, i.e., the except of the exchange eldinduced enhancement of the critical current [3,4] m ay occur in some range of h if exceeds de nite value (=4 <

For the case of SFcFS junctions with a short di usive constriction the following expression for the current may be obtained with the use of the Green's function technique [10]

$$I(') = {\begin{array}{c} Z_{1} \\ \\ \\ 0 \end{array}} (D)I(';D)dD;$$
 (11)

where I(';D) is determined by (8) with $R_0 = \text{$\sim$=e^2$}$ being the resistance of a single mode constriction, and the distribution of transparencies is determined by the function (D) = $(R_0 = 2R_N) = D$ (1 D)¹⁼² (R_N) is the normal state resistance of the constriction) which coincides with the density function found by D orokhov [17]. For the cases of parallel and antiparallel magnetizations Eqs.(8), (11) reduce to

$$I(') = \frac{16 \text{ T sin }'}{\text{eR}_{N}} \frac{x^{1}}{\sum_{n=0}^{\infty} \frac{\text{ReF}^{2}W}{n}} \frac{1}{\sum_{n=0}^{\infty} \frac{\text{Sin}^{2}}{\sum_{n=0}^{\infty} \frac{\text{Tr}}{\sum_{n=0}^{\infty} \frac{\text{Tr}}{\sum_{n=$$

where W $(x) = (1 x^2)^{1-2} \arctan[(1 x)=(1+x)^{\frac{1}{2}-2}]$. Note that in the case = 0 Eq.(12) reduces to the result obtained in Ref. [18]; for h = 0 Eqs.(12) coincide and in the lim it " $_b$ reproduce the Kulik-Omelyanchuk formula [19] for a discussed peculiar properties manifests itself also in junctions with discussed constriction.

In conclusion, we have developed a microscopic theory of supercurrent in SFcFS junctions with the arbitrary transparency of the constriction and di usive electron transport in the F layers for arbitrary angle—between the in plane exchange—elds in the F layers. We showed that the current-phase dependence m ay be strongly modi ed with the variation of: If the junction is in the " "state for identical orientation of magnetizations (= 0), the variation of may result in the transition between the "0" and " "states and disappearance of the $I_1 \sin'$ harm onic of the supercurrent at de nite value of . Nonm onotonic dependence of the critical current as a function of may occur for

both " " and "0" state of junction corresponding to the case of identical orientation of the magnetizations if the transparency of the junction is not small.

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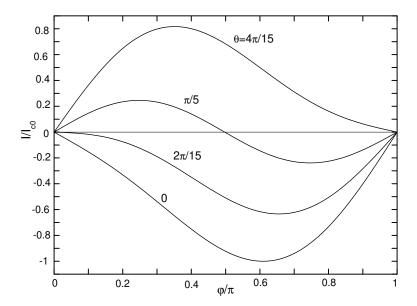


FIG.1: Fig1. Current-phase relations at various m isorientation angle for a SF-I+S junction with the transparency of the barrier D = 0.5 at h= = 1.5; T= = 0.15; $^{"}$ b= : For 0 = = 4 (0 <) the junction is in the " " state ("0" state). For in the vicinity of 0 second harm onic 1 2 sin (2') of the current dom inates, rst harm onics 1 1 sin ' vanishes at = 0 :

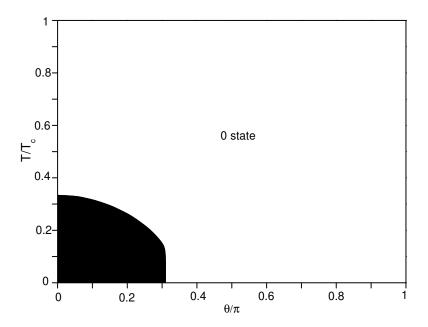


FIG. 2: Fig. . The (T;) phase diagram of a SF-I-FS junction with the transparency of the barrier D = 0.5 and h= = 1.5; "b = :Black region corresponds to the " " state of the junction.

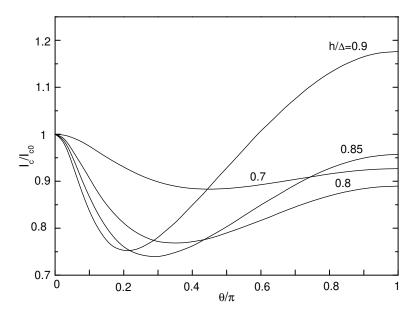


FIG. 3: Fig.3. Critical current as a function of the m isorientation angle normalized to its value at = 0 for a SF-IFS junction with the transparency of the barrier D = 0.5; $"_b =$; T = 0.01; these dependences correspond to "0" state of the junction.

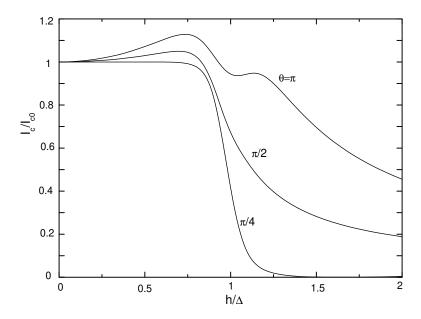


FIG. 4: Fig. A. Exchange eld dependence of the critical current I_c (h) (normalized to I_c (0) I_{c0}) at various m isorientation angle for SF-I-FS junction with the transparency of the barrier D = 0:1 at T = 0:01; " $_b$:

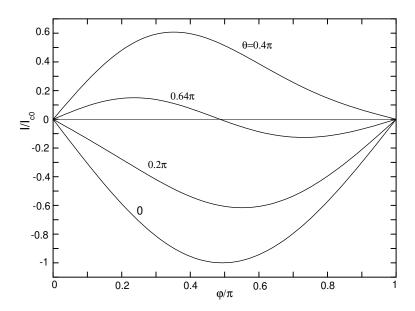


FIG. 5: Fig.5. Current-phase relations at various for a di usive SF-c-FS junction at h= = 1.5; $T=T_c=0.1$; $"_b=:$ For $_0=0.64$ ($_0<$) the junction is in the " " state ("0" state). For in the vicinity of $_0$ second harm onic $I_2\sin(2')$ of the current dominates, rst harm onics $I_1\sin'$ vanishes at $_0:$ 0: